Excellent Integrated System Limited

Stocking Distributor

Click to view price, real time Inventory, Delivery & Lifecycle Information:

<u>Fairchild Semiconductor</u> <u>MMBT4356</u>

For any questions, you can email us directly: sales@integrated-circuit.com



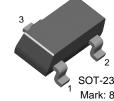
Datasheet of MMBT4356 - TRANS PNP 80V 0.8A SOT-23 Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com



MMBT4356

PNP General Purpose Amplifier

- This device is designed for use as general purpose amplifiers and switches requiring collector currents to 500mA.
- Sourced from process 67.
- See TN4033A for characteristics.



1. Base 2. Emitter 3. Collector

Absolute Maximum Ratings * T_A=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{CES}	Collector-Emitter Voltage	-80	V
V _{CBO}	Collector-Base Voltage	-80	V
V _{EBO}	Emitter-Base Voltage	-5.0	V
I _C	Collector current - Continuous	-800	mA
T _J , T _{stg}	Operating and Storate Junction Temperature Range	-55 ~ +150	°C

^{*} These ratings are limiting values above which the serviceability of any semiconductor device may be impaired

- These ratings are based on a maximum junction temperature of 150 degrees C.
 These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

Thermal Characteristics T_A=25°C unless otherwise noted

Symbol	Parameter	Max.	Units
P _D	Total Device Dissipation	350	mW
	Derate above 25°C	2.8	mW/°C
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	357	°C/W

©2002 Fairchild Semiconductor Corporation Rev. A1. November 2002



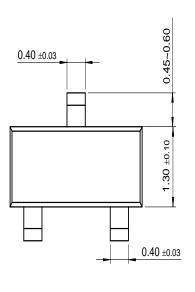
Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com

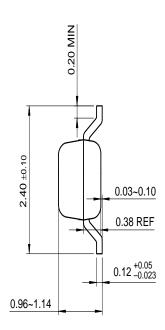
Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
Off Characte	eristics					
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage *	$I_C = -10 \text{mA}, I_B = 0$	-80			V
V _{(BR)CBO}	Collector-Base Breakdown Voltage	$I_C = -10\mu A, I_E = 0$	-80			V
V _{(BR)EBS}	Emitter-Base Breakdown Voltage	$I_C = -10\mu A, I_C = 0$	-5.0			V
I _{CBO}	Collector Cutoff Current	V _{CB} = -50V, I _E = 0 V _{CB} = -50V, I _E = 0, T _A = 75°C			-50 -5.0	nA μA
I _{CES}	Collector Cutoff Current	$V_{CB} = -50V, I_{E} = 0$			-50	nA
I _{EBO}	Emitter Cutoff Current	$V_{EB} = -4.0V, I_{C} = 0$			-100	μΑ
On Characte	eristics	, ==		•		
h _{FE}	DC Current Gain	$V_{CE} = -10V, I_{C} = -100\mu A$ $V_{CE} = -10V, I_{C} = -1.0mA$ $V_{CE} = -10V, I_{C} = -10mA$ $V_{CE} = -10V, I_{C} = -100mA$ $V_{CE} = -10V, I_{C} = -500mA$	25 40 50 40 30		250	
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = -150mA, I _B = -15mA I _C = -500mA, I _B = -50mA			-0.15 -0.5	V V
V _{BE(on)}	Base-Emitter On Voltage	I _C = -150mA, I _B = -15mA I _C = -500mA, I _B = -50mA			-0.9 -1.1	V V
Small Signa	I Characteristics					
C _{ob}	Output Capacitance	V _{CB} = -10V, f = 1MHz			30	pF
C _{ib}	Input Capacitance	V _{BE} = -0.5V, f = 1MHz			110	pF
h _{fe}	Small-Signal Current Gain	$V_{CE} = -10V, I_{C} = -50mA,$ f = 100MHz	1.0		5.0	
NF	Noise Figure	V_{CE} = -10V, I_{C} = -100 μ A R_{S} = 1k Ω , f = 1kHz B_{W} = 1Hz			3.0	dB
Switching C	haracteristics					
t _{on}	Turn-On Time	$V_{CC} = -30V, I_{C} = -500mA$	_		100	ns
t _{off}	Turn-Off Time	$I_{B1} = I_{B2} = -50 \text{mA}$			400	ns

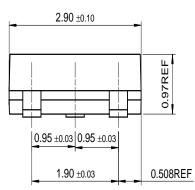
^{*} Pulse Test: Pulse Width ≤ 300μs, Duty ≤ 2.0%

Package Dimensions

SOT-23







Dimensions in Millimeters

Distributor of Fairchild Semiconductor: Excellent Integrated System Limited

Datasheet of MMBT4356 - TRANS PNP 80V 0.8A SOT-23

Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com

TRADEMARKS

The following are registered and unregistered trademarks Fairchild Semiconductor owns or is authorized to use and is not intended to be an exhaustive list of all such trademarks.

ACEx™	FACT™	ImpliedDisconnect™	PACMAN™	SPM™
ActiveArray™	FACT Quiet series™	ISOPLANAR™	POP™	Stealth™
Bottomless™	FAST [®]	LittleFET™	Power247™	SuperSOT™-3
CoolFET™	FASTr™	MicroFET™	PowerTrench [®]	SuperSOT™-6
$CROSSVOLT^{TM}$	FRFET™	MicroPak™	QFET™	SuperSOT™-8
DOME™	GlobalOptoisolator™	MICROWIRE™	QS™	SyncFET™
EcoSPARK™	GTO™	MSX™	QT Optoelectronics™	TinyLogic™
E2CMOSTM	HiSeC™	MSXPro™	Quiet Series™	TruTranslation™
EnSigna™	I^2C^{TM}	OCX^{TM}	RapidConfigure™	UHC™
Across the board.	Around the world.™	OCXPro™	RapidConnect™	UltraFET [®]
The Power Franc	hise™	OPTOLOGIC [®]	SILENT SWITCHER®	VCX™
Programmable Active Droop™		OPTOPLANAR™	SMART START™	

DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS.

LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF FAIRCHILD SEMICONDUCTOR CORPORATION.

As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, or (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in significant injury to the user.

2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

PRODUCT STATUS DEFINITIONS

Definition of Terms

Datasheet Identification	Product Status	Definition
Advance Information	Formative or In Design	This datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	This datasheet contains preliminary data, and supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
Obsolete	Not In Production	This datasheet contains specifications on a product that has been discontinued by Fairchild semiconductor. The datasheet is printed for reference information only.

©2002 Fairchild Semiconductor Corporation Rev. I1